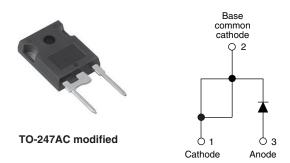
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Hyperfast Rectifier, 30 A FRED Pt[®]



PRIMARY CHARACTERISTICS					
I _{F(AV)} 30 A					
V _R	600 V				
V _F at I _F	1.34 V				
t _{rr} typ.	See Recovery table				
T _J max.	175 °C				
Package	TO-247AC modified				
Circuit configuration	Single				

FEATURES

- · Hyperfast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Single diode device
- AEC-Q101 qualified, meets JESD 201 class 1A whisker test



RoHS COMPLIANT HALOGEN FREE

• Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V _{RRM}		600	V		
Average rectified forward current	I _{F(AV)}	T _C = 116 °C	30	٨		
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	300	A		
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-		
Forward valtage	N	I _F = 30 A	-	2.0	2.6	V	
Forward voltage V _F	v _F	I _F = 30 A, T _J = 150 °C	-	1.34	1.75		
		V _R = V _R rated	-	0.3	50		
Reverse leakage current I _R		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	60	500	μA	
Junction capacitance	CT	V _R = 600 V	-	33	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	3.5	-	nH	

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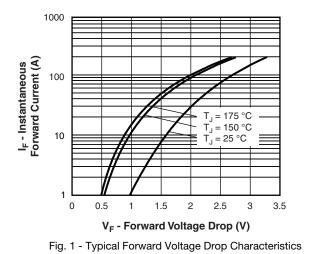
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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 $^{\circ}$ C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t =$	= 50 A/µs, V _R = 30 V	-	28	35			
Reverse recovery time	t _{rr}	$T_J = 25 \ ^\circ C$	I _F = 30 A dI _F /dt = 200 A/μs V _R = 200 V	-	31	-	ns		
		T _J = 125 °C		-	77	-			
Deals receivers aurrent	I _{RRM}	T _J = 25 °C		-	3.5	-	^		
Peak recovery current		T _J = 125 °C		-	7.7	-	A		
Deverse version shows	0	T _J = 25 °C		-	65	-	nC		
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	345	-	nc		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C	
Thermal resistance, junction to case per leg	R _{thJC}		-	0.5	0.9		
Thermal resistance, junction to ambient per leg	R _{thJA}	Typical socket mount	-	-	70	°C/W	
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.4	-		
Weight			-	6.0	-	g	
Weight			-	0.22	-	oz.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Marking device		Case style TO-247AC modified		30EP	H06H		

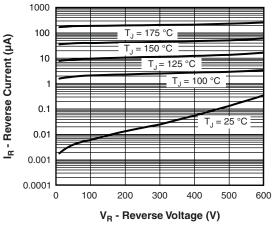
VS-30EPH06HN3

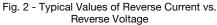
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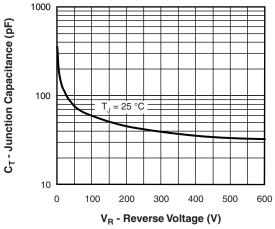


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

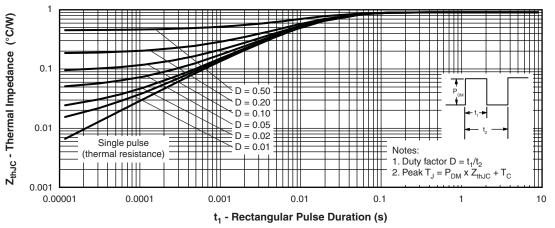
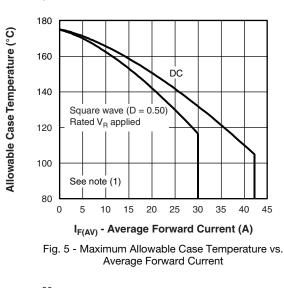


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics





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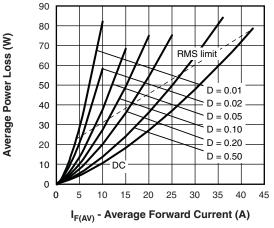
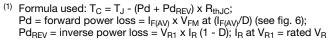


Fig. 6 - Forward Power Loss Characteristics

Note



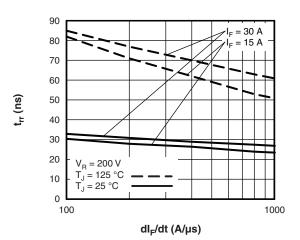


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

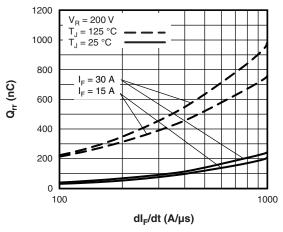


Fig. 8 - Typical Stored Charge vs. dl_F/dt

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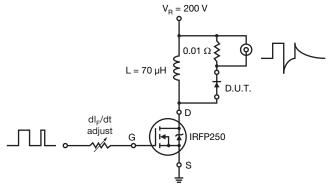


Fig. 9 - Reverse Recovery Parameter Test Circuit

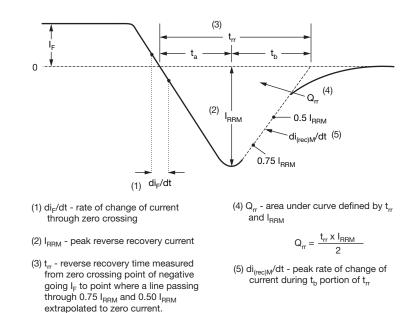


Fig. 10 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code	VS-	30	Е	Р	н	06	Н	N3
		(2)	(3)	(4)	(5)	(6)	(7)	(8)
		- Cur	rent rati	niconduo ng (30 =	= 30 A)	oduct	Ŭ	Ŭ
	4	E = - Pac	single o kage:	-				
		- H=	hyperfa	ast recov ing (06 =	/ery)		
	7 - 8 -	- Env	ironmer	101 qua ntal digit jen-free,	:	complia	ant, and	totally le

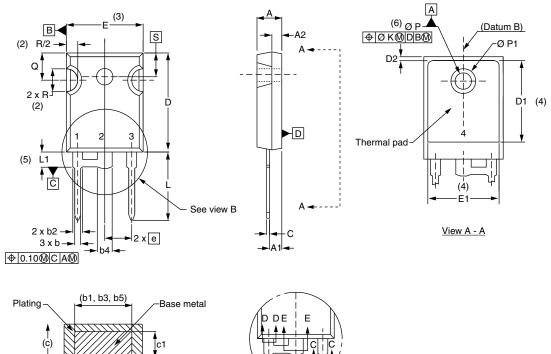
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-30EPH06HN3	25	500	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95253			
Part marking information	www.vishay.com/doc?95442			
SPICE model	www.vishay.com/doc?96573			



TO-247AC modified

DIMENSIONS in millimeters and inches



Section C - C, D - D, E - E

(4)

(b b2 b4)

Ξ	

View B

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIDOL	MIN.	MAX.	MIN.	MAX.	NUTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
с	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.530	-	
е	5.46	BSC	0.215	BSC	
ØК	0.2	254	0.010		
L	14.20	16.10	0.559	0.634	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	BSC	

Notes

- ⁽¹⁾ Dimensioning and tolerance per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- ⁽⁴⁾ Thermal pad contour optional with dimensions D1 and E1
- ⁽⁵⁾ Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- ⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension c

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